

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

Features

- Low conduction loss due to low VF
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

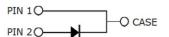
Applications

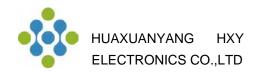
- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

| Ordering Part Number | Package | Marking |
|-------------------------|-----------|------------|
| HC3D10120E | TO-252-2L | HC3D10120E |







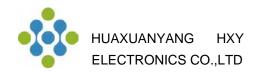


Maximum Ratings (at Tj = 25 °C, unless otherwise specified)

| Parameter | Symbol | Value | Unit |
|---|------------------|----------------|------|
| Repetitive Peak Reverse Voltage | Vrrm | 1200 | V |
| Surge Peak Reverse Voltage | Vrsm | 1200 | V |
| DC Peak Reverse Voltage | VR | 1200 | V |
| Continuous Forward Current Tc = 25°C Tc = 135°C Tc = 160°C | lF | 30 15 10 | А |
| Repetitive Peak Forward Surge Current Tc = 25°C,tp=10ms,Half Sine Pulse Tc = 110°C,tp=10ms,Half Sine Pulse | İFRM | 57 41.5 | А |
| Non-Repetitive Forward Surge Current $Tc = 25^{\circ}C, t_p=10 \text{ms}, Half Sine Pulse }$ $Tc = 110^{\circ}C, t_p=10 \text{ms}, Half Sine Pulse }$ | Ігѕм | 90 69.5 | А |
| i^2 dt value $T_C = 25^{\circ}C, t_p = 10 ms, Half Sine Pulse T_C = 110^{\circ}C, t_p = 10 ms, Half Sine Pulse$ | ∫ i²dt | 40.5 24 | A²s |
| Power dissipation $Tc = 25^{\circ}C$ $Tc = 110^{\circ}C$ | Ptot | 115 50 | W |
| Operating junction Range | Tj | -55 to +175 | °C |
| Storage temperature Range | T _{stg} | -55 to +150 | °C |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
|--------------------------------------|--------|-------|------|
| Thermal resistance, junction - case. | RthJC | 1.30 | °C/W |



Electrical Characteristic (at Tj = 25 °C, unless otherwise specified)

| Parameter | Symbol | | Value | | Unit | Test Condition |
|-------------------------|----------|------|-------|------|-------|--|
| 1 arameter | Cyllibol | min. | typ. | max. | Oilit | rest condition |
| | | | | | | I _F =2A |
| Forward Voltage | VF | - | 1.4 | 1.7 | V | T _j =25°C |
| | | - | 2.0 | - | | Tj=175°C |
| | | | | | | V _R =1200V |
| Reverse Current | lr | - | - | 100 | μΑ | T _j =25°C |
| | | - | - | 200 | | T _j =175°C |
| | | | | | | V _R =800V,T _j =25℃ |
| Total Capacitive Charge | Qc | - | 48 | - | nC | $Q_C = \int_0^{V_R} C(V) dV$ |
| | | | | | | Tj=25℃, f=1MHz |
| T 0 | | - | 695 | - | _ | V _R =0V |
| Total Capacitance | С | - | 46 | - | pF | V _R =400V |
| | | - | 35 | - | | Vr=800V |

Characteristics Curve:

Fig 1: Forward Characteristics

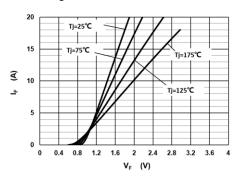


Fig 3: Current Derating

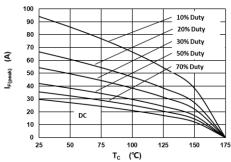


Fig 2: Reverse Characteristics

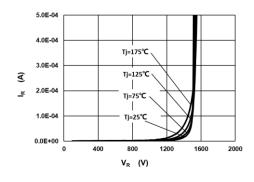
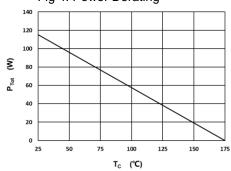


Fig 4: Power Derating



0

0.1

800 700 600 500 200 100

10

V_R (V)

100

1000

Fig 5: Capacitance vs. Reverse Voltage

Fig 6: Reverse Charge vs. Reverse Voltage

60
50
40
20
10
0
200
400
600
800
1000
1200
V_R (V)

Fig 7: Typical Capacitance Stored Energy

25

20

3

15

0

0

200

400

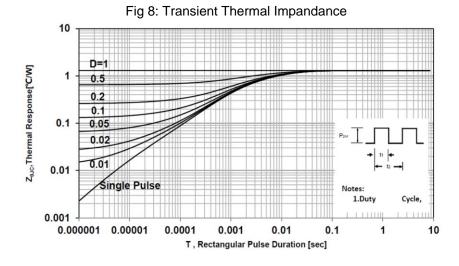
600

800

1000

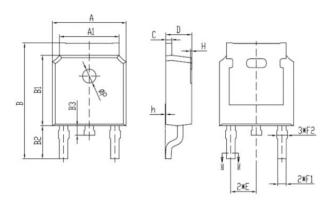
1200

V_R (V)



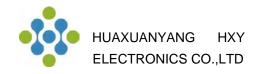
Package Dimensions

Package TO-252-2L





| 项目 | 规范(mm) | | |
|----|--------|-------|--|
| | MIN | MAX | |
| A | 6.50 | 6.70 | |
| A1 | 5.16 | 5.46 | |
| В | 9.77 | 10.17 | |
| B1 | 6.00 | 6.20 | |
| B2 | 2.60 | 3.00 | |
| B3 | 0.70 | 0.90 | |
| C | 0.45 | 0.61 | |
| D | 2.20 | 2.40 | |
| E | 2.186 | 2.386 | |
| F1 | 0.67 | 0.87 | |
| F2 | 0.76 | 0.96 | |
| Н | 0.00 | 0.30 | |
| h | 0.00 | 0.127 | |
| L | 6.50 | 6.70 | |
| φР | 1.10 | 1.30 | |



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